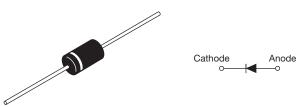
Vishay Semiconductors

Schottky Rectifier, 1.1 A



www.vishay.com

DO-204AL

| PRODUCT SUMMARY | | | | | |
|----------------------------------|----------------------|--|--|--|--|
| Package | DO-204AL (DO-41) | | | | |
| I _{F(AV)} | 1.1 A | | | | |
| V _R | 90 V, 100 V | | | | |
| V _F at I _F | See Electrical table | | | | |
| I _{RM} | 1.0 mA at 125 °C | | | | |
| T _J max. | 150 °C | | | | |
| Diode variation | Single die | | | | |
| E _{AS} | 1.0 mJ | | | | |

FEATURES

- · Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

DESCRIPTION

The VS-11DQ... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | |
|-----------------------------------|-------------------------------|---------------------------|----|--|--|--|--|--|
| SYMBOL | CHARACTERISTICS | CHARACTERISTICS VALUES UN | | | | | | |
| I _{F(AV)} | Rectangular waveform | 1.1 | А | | | | | |
| V _{RRM} | | 90/100 | V | | | | | |
| I _{FSM} | t _p = 5 μs sine | 85 | А | | | | | |
| V _F | 1 Apk, T _J = 25 °C | 0.85 | V | | | | | |
| TJ | Range | - 40 to 150 | °C | | | | | |

| VOLTAGE RATINGS | | | | | | | |
|--------------------------------------|------------------|-----------|--------------|-----------|--------------|-------|--|
| PARAMETER | SYMBOL | VS-11DQ09 | VS-11DQ09-M3 | VS-11DQ10 | VS-11DQ10-M3 | UNITS | |
| Maximum DC reverse voltage | V _R | 90 | 90 | 100 | 100 | V | |
| Maximum working peak reverse voltage | V _{RWM} | 90 | 90 | 100 | 100 | v | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|--|--------------------|---|---|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | | |
| Maximum average forward current See fig. 4 | I _{F(AV)} | 50 % duty cycle at T_{C} = 75 °C, rectangular waveform | | 1.1 | | | |
| Maximum peak one cycle non-repetitive surge current | | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with rated | 85 | А | | |
| See fig. 6 | IFSM | 10 ms sine or 6 ms rect. pulse | V_{RRM} applied | 14 | | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH | | 1.0 | mJ | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 0.5 | А | | |

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COMPLIANT

HALOGEN

FREE

Available

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| ELECTRICAL SPECIFICATIONS | | | | | | |
|--|--------------------------------|---|---------------------------------------|------|------|--|
| PARAMETER | SYMBOL | TEST CO | TEST CONDITIONS | | | |
| | V _{FM} ⁽¹⁾ | 1 A | T ₁ = 25 °C | 0.85 | V | |
| Maximum forward voltage drop See fig. 1 | | 2 A | 1j=25 0 | 0.96 | | |
| | | 1 A | T.I = 125 °C | 0.68 | | |
| | | 2 A | $1_{\rm J} = 125$ C | 0.78 | | |
| Maximum reverse leakage current | I _{BM} ⁽¹⁾ | T _J = 25 °C | $V_{\rm B}$ = Rated $V_{\rm B}$ | 0.5 | mA | |
| See fig. 2 | | T _J = 125 °C | V _R = naleu V _R | 1.0 | ША | |
| Typical junction capacitance | C _T | V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C | | 35 | pF | |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body 8.0 | | | nH | |
| Maximum voltage rate of change | dV/dt | Rated V _R 10 000 V/μs | | | V/µs | |

Note

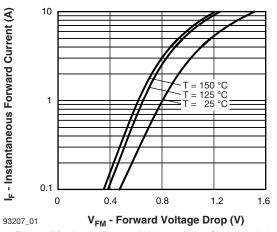
 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|--|---|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum junction and storage temperature range | T _J ⁽¹⁾ , T _{Stg} | | - 40 to 150 | °C | | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | R _{thJA} DC operation Without cooling fin | | °C/W | | |
| Typical thermal resistance, junction to lead | R _{thJL} | DC operation See fig. 4 | 81 | 0/11 | | |
| Approvimate weight | | | 0.33 | g | | |
| Approximate weight | | | 0.012 | oz. | | |
| Marking device | | | 11DQ09 | | | |
| | | Case style DO-204AL (DO-41) | 11DQ10 | | | |

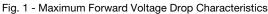
Note

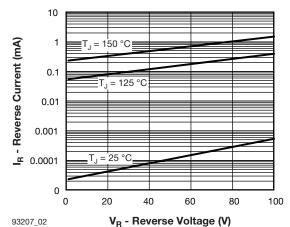
 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

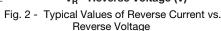
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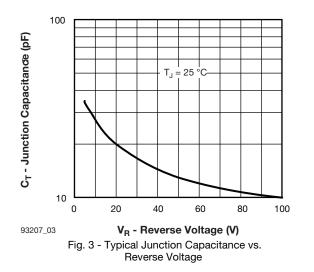


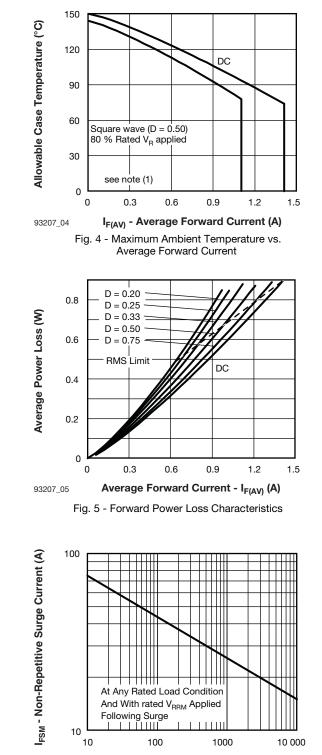
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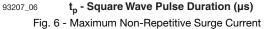












Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} \times I_{R} (1 - D); I_{R} at V_{R1} = 80 \% rated V_{R1} \times I_{R1} = 10 \% rated V_{R1} \times I_{R1} \times$

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ORDERING INFORMATION TABLE

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| | | | | | | | | _ |
|-------------|-----|------|-----------|------------|----------|---------------|----------|--|
| Device code | VS- | 11 | D | Q | 10 | TR | -M3 | |
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | |
| | 1 - | Vish | nay Sem | niconduc | tors pro | duct | | |
| | 2 - | 11 = | = 1.1 A (| axial an | d small | packag | es - cur | rrent is x 10) |
| | 3 - | D = | DO-41 | package |) | | | |
| | 4 - | Q = | Schottk | xy Q se | ries | | Г | |
| | 5 - | 10 = | Voltag | e ratings | s ——— | | | 09 = 90 V 10 = 100 V |
| | 6 - | TR | = Tape | and reel | packag | е | L | |
| | | Nor | ie = Bull | k packa | ge | | | |
| | 7 - | Env | ironmer | ntal digit | | | | |
| | | • No | one = Le | ead (Pb) | -free an | d RoHS | 6 compl | liant |
| | | - N | 0 - 11-1 | - | Dell | • • • • • • • | 1 | and the survey line of the second line |

• -M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|------------------|------------------------|-----------------------|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | |
| VS-11DQ09 | 1000 | 1000 | Bulk | | |
| VS-11DQ09TR | 5000 | 5000 | Tape and reel | | |
| VS-11DQ09-M3 | 1000 | 1000 | Bulk | | |
| VS-11DQ09TR-M3 | 5000 | 5000 | Tape and reel | | |
| VS-11DQ10 | 1000 | 1000 | Bulk | | |
| VS-11DQ10TR | 5000 | 5000 | Tape and reel | | |
| VS-11DQ10-M3 | 1000 | 1000 | Bulk | | |
| VS-11DQ10TR-M3 | 5000 | 5000 | Tape and reel | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?95241 | | | | |
| Part marking information | www.vishay.com/doc?95304 | | | | |
| Packaging information | www.vishay.com/doc?95338 | | | | |

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27.0 (1.06) MIN. (2 places)

1.27 (0.050) MAX.

Flash (2 places)

2.70 (0.106)

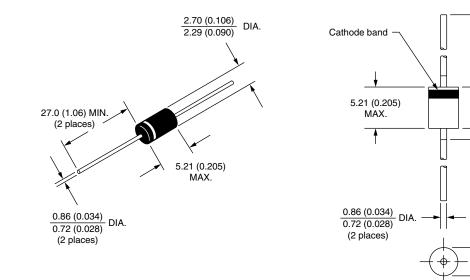
2.29 (0.090)

DIA.



Axial DO-204AL (DO-41)

DIMENSIONS in millimeters (inches)





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